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Prepared for the U.S. Department of Energy Under DOE Idaho Operations Office Contract DE-AC07-05ID14517



Basic Energy Sciences Program

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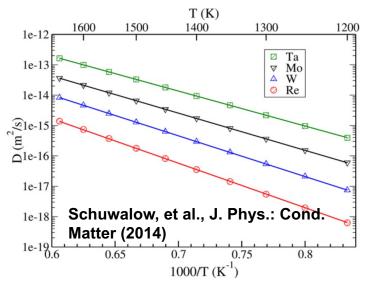
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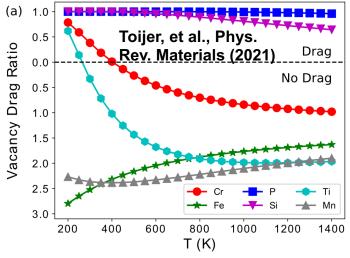
"The work was supported by the U.S. Department of Energy, Office of Science, Materials Sciences and Engineering Division."

Literature

Several DFT studies on solute diffusion in FCC Ni

- DFT + five-frequency model:
 - interactions limited to the 1st nn.
 - Tucker, et al., J. Nucl. Mater. (2010): Cr and Fe solutes
 - Hargather et al., Acta Materialia (2018): diffusivities of 26 solutes in FCC Ni
- DFT + KMC :
 - Schuwalow et al. calculated diffusivities of Mo, Re, W, and Ta solutes in FCC Ni
- DFT + SCMF :
 - taking into account kinetic correlations to calculate Onsager transport coefficients.
 - Toijer et al. studied the solute-point defects interaction in FCC Ni using DFT (solutes: Cr, Fe, Si, Al, P, and Mn): vacancy drag and segregation tendencies





Methodology

• In this work:

- we adopt the methodology of **<u>DFT+SCMF</u>** to investigate the segregation tendencies of Co, Cr, Mo, Re, W, and Ta solutes in Ni-based superalloys
- we extend this model to include the segregation tendencies <u>under strain</u> using the linear elasticity theory as implemented in the KineCluE code
- Using density functional theory (DFT):
 - → vacancy-solute interactions: formation, binding and migration energies
 - → phonon calculations to obtain attempt frequencies (diffusion prefactors) and vacancy formation entropy
- Using self-consistent mean field theory (SCMF):
 - → cluster transport coefficients and partition functions

DFT Computational Details

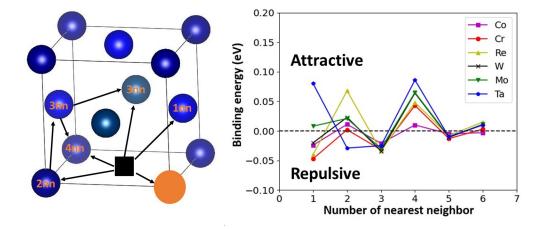
- PAW pseudopotentials as implemented in VASP
 - GGA-PBE exchange-correlation functionals
 - 108-atom and 192-atom supercells
- Climbing-image NEB to get the saddle point energy for atomic jumps
 - One intermediate image
- Frozen phonons method to calculate the attempt frequencies
 - 0.02 Å atomic displacements to get force constants

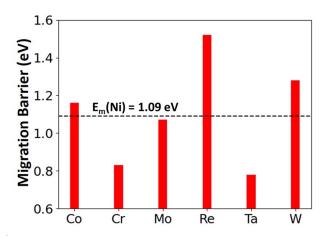
Vacancy-Solute Interactions

- Vacancy-solute interactions up to the 4th nn are considered
- For each solute, the migration barrier for 8 jumps are calculated:
 - vacancy-solute exchange
 - 7 vacancy jumps
 (dissociation/association and reorientation)
 (1nn→1nn, 1nn→2nn, 1nn→3nn, 1nn→4nn, 2nn→3nn, 3nn→3nn, 3nn→4nn)

Findings:

- Ta, Cr, and Mo are relatively fast diffusers
- Co, W, and Re are relatively slow diffusers.





SCMF Computational Details

Onsager matrix
$$\binom{J_V}{J_B} = \frac{-1}{k_B T} \begin{pmatrix} L_{VV} & L_{VB} \\ L_{VB} & L_{BB} \end{pmatrix} \begin{pmatrix} \nabla \mu_V \\ \nabla \mu_B \end{pmatrix}$$

Cluster expansion:

$$\begin{pmatrix} L_{VV} & L_{VB} \\ L_{VB} & L_{BB} \end{pmatrix} = C (f_V \begin{pmatrix} L_{VV}^{(V)} & 0 \\ 0 & 0 \end{pmatrix} + f_{VB} \begin{pmatrix} L_{VV}^{(VB)} & L_{VB}^{(VB)} \\ L_{VB}^{(VB)} & L_{BB}^{(VB)} \end{pmatrix})$$
 Contribution from clusters with vacancies with vacancy-solute pairs

- f_V and f_{VB} are the fractions of vacancies and vacancy-solute pairs, respectively, and are obtained from the SCMF partition functions
- Kinetic range $(r_{kin}) = 4$ lattice constants (after performing convergence tests)
- Dilute limit: maximum solute concentration [B] using this cluster size is 0.1 at. %

Cluster fractions

$$f_V = \frac{C_V - C_{corr}}{C}, f_{VB} = \frac{C_{VB}}{C}$$

$$C_{V} = Z_{V}[V] = Z_{V}e^{\frac{-E_{form}^{vac}}{k_{B}T}}e^{\frac{S_{form}^{vac}}{k_{B}T}}$$

$$C_{VB} = Z_{VB}[V][B]$$

 Z_{VB} : pair partition function

$$Z_{VB} = \sum_{i} e^{\frac{E_{bind}^{i}}{k_B T}}$$

$$C_{corr} = Z_{VB}^0[V][B]$$

(sites that single vacancies cannot occupy because of the geometrical definition of the vacancy-solute pair)

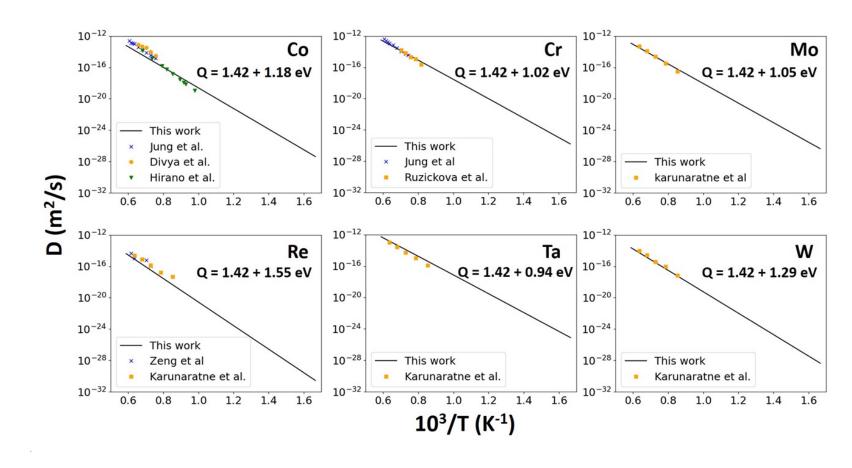
 Z_{VB}^{0} : non-interacting cluster partition function (# of possible pair configurations within r_{kin} .

Solute Diffusivities

• In the dilute limit:

$$D_B = \frac{L_{BB}}{[B]}$$

 Good agreement of calculations with experimental data



Solute vacancy drag and partial diffusion coefficient ratio

We analyze flux coupling from transport coefficients

- → Vacancy drag ratio (G) indicates if a solute
 - follows the vacancy in its migration (G>0) or
 - diffuses in the opposite direction (G<0)
- →PDC ratio describes the diffusion of solute atoms relative to matrix atoms
 - -ve PDC ratio: vacancy drag → solute enrichment at sinks
 - +ve PDC ratio: inverse Kirkendall
 - PDC ratio > 1 : solute depletion at sinks (favorable solute-vacancy exchange)
 - <u>0 < PDC ratio < 1 : solute enrichment</u> (slower than the host atoms, so effectively enriched)

$$G = \frac{L_{VB}^{(VB)}}{L_{BB}^{(VB)}}$$

$$PDC = \frac{1 - C_B}{C_B} \frac{L_{VB}}{L_{AV}}$$

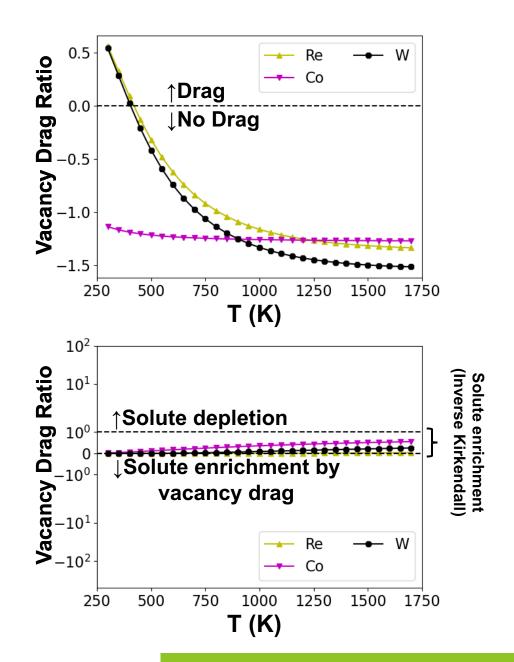
Segregation Tendencies (A) Slow diffusers

Re and W :

- dragged by vacancies at low temperature below ~400 K
- At higher temperatures, they move opposite to the vacancy flux but are enriched (inverse Kirkendall mechanism)

• <u>Co:</u>

- not dragged by vacancies at any temperature due to weak binding
- Enrichment by inverse Kirkendall mechanism



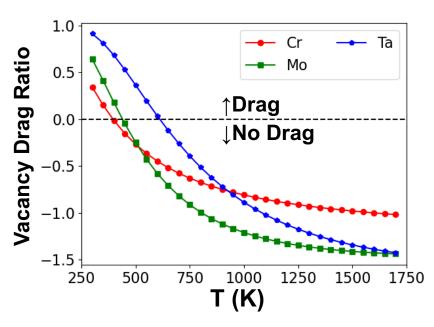
Segregation Tendencies (B) Fast diffusers

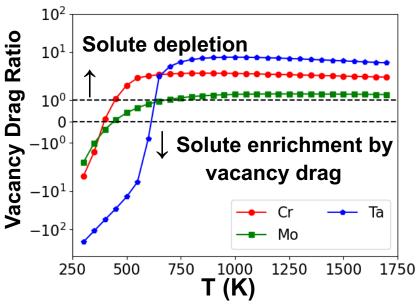
Cr and Mo:

- dragged by vacancies at low temperature below ~400 K (enriched)
- Cr depletion at T > 500 K
- Mo depletion at T > 600 K

• <u>Ta:</u>

- Dragged by vacancies up to 600 K due to strong binding
- Ta depletion above 650 K





Strain Effects

Linear elasticity theory approach

- Instead of repeating DFT calculations on strained supercells:
- The binding and migration energies under strain tensor ε_{ij} :

$$E_b^{x}(\varepsilon = \varepsilon_{ij}) = E_b^{x}(\varepsilon = 0) + P_{ij}^{x}\varepsilon_{ij}$$
$$E_m^{x_1 \to x_2}(\varepsilon = \varepsilon_{ij}) = E_m^{x_1 \to x_2}(\varepsilon = 0) - P_{ij}^{ts(x_1 \to x_2)}\varepsilon_{ij}$$

- P_{ij}^{x} is the DFT elastic dipole tensor of a defect configuration (x)
- $P_{ij}^{ts(x1\Rightarrow x2)}$ is the DFT elastic dipole tensor of a transition state between two configurations x1 and x2
- In this work, we are only considering a tensile hydrostatic strain $\begin{pmatrix} +e & 0 & 0 \\ 0 & +e & 0 \\ 0 & 0 & +e \end{pmatrix}$

Segregation Tendencies Under Strain

Two factors control the sensitivity of strain effect on the segregation tendency

1. Relative mobility of the solute

- The segregation tendency of slow diffusers (Co, W, Re) is not affected by strain (even if the vacancy drag ratio changes)
- The segregation tendency of fast diffusers (Mo, Cr, Ta) is significantly affected by strain

2. The stress introduced by the solute in the lattice (relaxation volume)

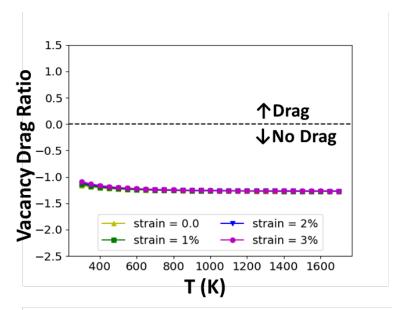
 The vacancy drag of solutes with higher residual stresses have higher sensitivity to strain

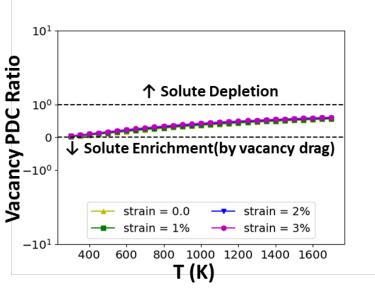
Segregation Tendencies Under Strain: (A) Slow diffusers

(1) <u>Co</u> (Slow diffuser, zero residual stress)

- No change in vacancy drag (because of the zero elastic dipole tensor)
- No change in segregation tendency

	E _m (eV)	Stress (eV)	Solute-vacancy pair stress (eV)
Vacancy	1.09	-4.6 /	-
Co	1.16	0.0 / (No residual stress)	$\begin{pmatrix} -4.7 & 0 & 0 \\ 0 & -4.6 & 0.11 \\ 0 & 0.11 & -4.6 \end{pmatrix}$



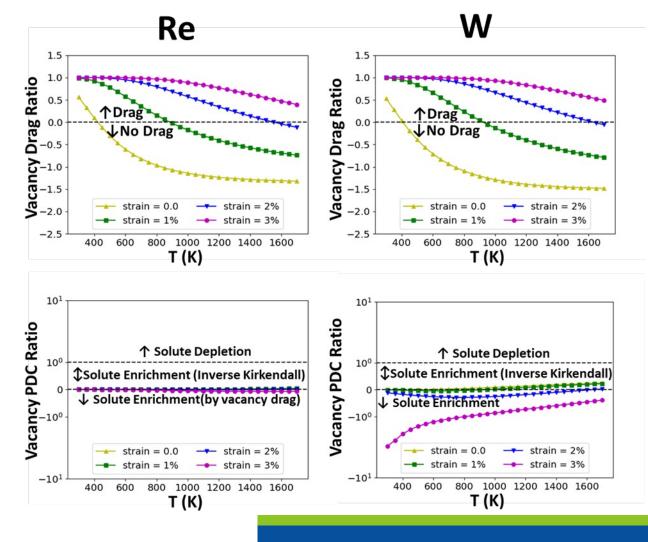


Segregation Tendencies Under Strain: (A) Slow diffusers

(2) Re and W(Slow diffusers, non-zero residual stress)

- Although vacancy drag increases with tensile strain, Re enrichment is minimally affected (too slow to be strongly dragged)
- W enrichment increases by vacancy drag mechanism (faster than Re)

	E _m (eV)	Stress (eV)
Re	1.52 (slowest)	5.0 /
W	1.28	5.5 /



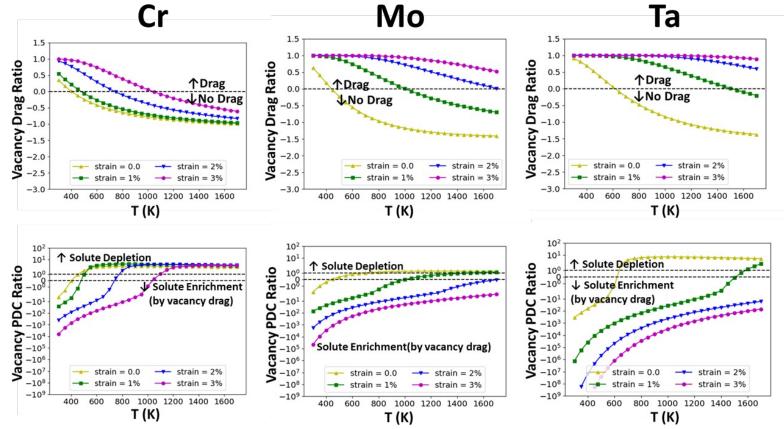
Segregation Tendencies Under Strain:

(B) Fast diffusers

(3) <u>Cr, Mo, and Ta</u> (fast diffusers)

- Multiple orders of magnitudes changes in PDC ratio
- The increase of enrichment tendency is the highest for Ta (fastest & highest residual stress)

	E _m (eV)	stress (eV)
Мо	1.07	5.4 /
Cr	0.84	2.7 /
Та	0.78	7.9 /



Summary and Conclusions

- Solute-vacancy defect energetics in FCC Ni were calculated using first-principles calculations (DFT)
- The Onsager transport coefficients were evaluated using the SCMF approach
- Fast diffusers (Ta, Cr, and Mo)
 - depleted at sinks due to favorable vacancy-solute exchange (inverse Kirkendall) at high temperatures
 - enriched at sinks by vacancy drag at low temperatures
- Slow diffusers (Co, Re, and W)
 - Enriched at sinks by the inverse Kirkendall mechanism
- The segregation tendency of fast-diffusing solutes is more sensitive to strain



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